

FEATURE



- Reduction in required real estate(more than 50%)
- Reduction cost, Space and time for placement on PCB
- Reduction in number of solder joints
- Easier PCB design
- Reduced waste from tape and reel packaging process
- Protect EMI bypassing digital signal line noise

PART NUMBER CODE



- (1) Samsung Multilayer Ceramic Chip Capacitor
- (2) Capacitor Array
- (3) Array Type
- (4) Capacitance Temperature Characteristics
- (5) Nominal Capacitance
- (6) Capacitance Tolerance(NPO:"K" only, X7R:"M" only)
- (7) Rated Voltage
- (8) Thickness Option
- (9) Packaging Type("E" only)



CONFIGURATION AND DIMENSIONS



Туре	Size(inch)	Element	L	w	т	BW	sw	Р
4	0612	4	3.2+/-0.2	1.6+/-0.2	1.35 max	0.4+/-0.2	0.1 min	0.8+/-0.2

ARRAY TYPE(SIZE)

CODE	NUMBER OF CAPS	SIZE			
	4	UNIT(mm)	UNIT(inch)		
4	4	3.2 x 1.6	06 x 12		

CAPACITANCE TEMPERATURE CHARACTERISTIC

CODE	TEMP. CHAR	TEMP. RANGE	
# C	COG	0+/-30 (PPM/C)	-55 ~ +125 C
В	X7R	+/-15%	-55 ~ +125 C
F	Y5V	+22~ -82%	-30 ~ + 85 C

* Temperature Characteristics

Temperature Characteristics	below 2.0pF	2.2 ~ 3.9pF	above 4.0pF	above 10pF
#C	СК	CJ	СН	CG/CH

K : +/- PPM/c J : +/-120 PPM/c H : +/-60 PPM/c G : +/-30 PPM/c

NOMINAL CAPACITANCE

The value of nominal capacitance is expressed in pico-Farad(pF) with a three-digit number. The first two digits denote significant figures and the last digit denotes the multiple of 10 in pF. For values below 1pF, the letter "R" is used as the decimal point and the last digit becomes significant.

example100 = 10 x 10^0 = 10pF222 = 22 x 10^2 = 2200pF020 =2 x 10^0 = 2pF1R5 = 1.5pF



CAPACITANCE TOLERANCE

CHAR.	т	NOMINAL CAPACITANCE	
с	* J (+/- 5 %) K (+/-10 %)	MORE THAN 10pF	E-12 SERIES
В	* J (+/-5%), * K (+/-10	E-6 SERIES	
F	Z (+80 ~ -20%)	E-6 SERIES	

Please Consult us for special tolerances. *: Option

RATED VOLTAGE

Symble	Rated Voltage(Vdc)
0	16V
Α	25V
В	50V
С	100V

THICKNESS OPTION

Symbol	Description of the Code
Ν	Standard thickness (please refer to standard thickness table on next page)
Α	Thinner than standard thickness
В	Thicker than standard thickness

PACKAGING TYPE

Symbol	Packaging
E	Embossed Tape, 7" Reel



CAPACITANCE RANGE

					Т	HICKNESS	0.85+/-0.1mm
Temperature	сн		X7R			Y5V	
Characteristics	UII						
Rated Voltage(DC)	50V	16V	25V	50V	16V	25V	50V
Capacitance(pF)							
10							
15							
22							
33							
47							
68							
100							
150							
220							
330							
470							
680							
1000							
1500							
3300							
4700							
10000							
22000							
47000							
100000							
150000							

Please contact us for special capacitance and high voltage(100V)



RELIABILITY AND TEST CONDITIONS

NO	ITEM PERFORMANCE				ANCE	TEST CONDITION				
1	APPEA	RANCE	NO ABNO	NRMAL EXTER	RIOR	THROUGH MICRO	DSCOPE(x10)			
2	INSULATION	RESISTANCE	10,000Mohm OR 500Mohm uF PRODUCT WHICHEVER IS SMALLER. (RATED VOLTAGE IS BELOW 16V 10,000Mohm OR 100Mohm uF)			RATED VOLTAGE SHALL BE APPLIED. MEASUREMENT TIME IS 60 ~ 120 SEC.				
3	WITHSTANDING VOLTAGE		NO DIELECTRIC BREAKDOWN OR MECHANICAL BREAKDOWN.			CLASS I:300% OF 1~5 SEC, CLASS VOLTAGE FOR 1 THAN 50mA CUR	CLASS I:300% OF THE RATED VOLTAGE FOR 1~5 SEC, CLASS II:250% OF THE RATED VOLTAGE FOR 1~5 SEC IS APPLIED LESS THAN 50mA CURRENT.			
						CAPACITANCE	FREQUENCY	VOLTAGE		
		CLASS	WITH TOLE	IN THE SPEC RANCE.	CIFIED	1,000pF AND BELOW	1MHz+/-10%	0.5 ~ 5 Vrms		
4	CAPACITANCE					MORE THAN 1,000pF	1.0+/-0.2Vrms			
		CLASS	WITH	IN THE SPEC	SIFIED	FREQUE	NCY	VOLTAGE		
		11	TOLE	RANCE.		1KHz+/-	10%	1.0+/-0.2Vrms		
						CAPACITANCE	FREQUENCY	VOLTAGE		
5	Q	CLASS	30pF AND OVER : Q >=1,000 LESS THAN 30pF: Q >=400 +20C			1,000pF AND BELOW	1MHz+/-10%	0.5 ~ 5 Vrms		
				(C : CAPACI	TANCE)	MORE THAN 1,000pF		1.0+/-0.2Vrms		
			СНАВ	25V and	16\/	FREQUE	NCY	VOLTAGE		
		CLASS		0.025 MAX	0.035 MAX					
6	Tan delta	II II	F	0.05 MAX	0.07 MAX (C<1.0uF) 0.09 MAX (C>=1.0uF)	1KHz+/-10%		1.0+/-0.2Vrms		
		STRENGTH			EELING SHALL	A 500g.f PULL FORCE SHALL BE				
	OF TERM	IINATION	OCCUR C	ON THE TERM	AINAL	APPLIED FOR 10+/-1SECOND.				
7	01 121	ELECTRODE.								
							₽₽	500g.f		
						BENDING SHALL	BE APPLIED T	O THE		
						LIMIT(1mm) WITH 0.3mm/SEC.				
							R=340			
8	BENDING STRENGTH	APPEARANCE NO MECHANICAL DAMAGE SHALL OCCUR.		IAGE SHALL	50					
								DING IIT		



Multilayer Chip Capacitors - Array

NO	Г	PERFORMANCE				TEST CONDITION			
9	SOLDE	MORE THAN 75% OF THE TERMINAL SURFACE IS TO BE SOLDERED NEWLY, SO METAL PART(A) DOES NOT COME OUT OR DISSOLVE.				SOLDER TEMPERATURE : 230+/-5C SOLDER : H63A FLUX : ROSIN PRE-HEATING : AT 80~120C FOR 10~30SEC.			
		APPEARANCE	NO M	ECHAN	ICAL DAMAGE	DIP :	SOL	DER TEMPERA	TURE OF
			CHARACTER		CAP. CHANGE	DIP T	TIME	:10+/-1SEC.	
	DEDIOTANOE	CAPACITANCE	CLASS I CLASS			EACH TERMINATION SHALL BE FULLY IMMERSED AND PREHEATED AS FOLLOWING:			ALL BE FULLY ATED
	TO		CLASS II		WITHIN +/-7.5%	STEP		TEMP.(C)	(SEC.)
10	SOLDERING	SOLDERING		F	WITHIN +/-20%		1	80~100	60
	HEAT	Q	30pF AND C	OVER :	Q>= 1000		2	150~180	60
		Tan delta	TO SATISFY	/ THE :	SPECIFIED	MEAS	SURE	AT ROOM TE	MP. AFTER
		CLASS II	INITIAL VAL	UE.		COOLING FOR			
		INSULATION	TO SATISFY	/ THE :	SPECIFIED	CLASS I : 24 +/- 2 HOURS			
		RESISTANCE	INITIAL VAL	UE.		CLASS II : 48 +/- 4 HOURS			
		WITHSTANDING	TO SATISFY	/ THE S	SPECIFIED				
		VOLTAGE	INITIAL VAL	UE.					
		APPEARANCE	NO MECHANICAL DAMAGE SHALL OCCUR.			THE CAPACITOR SHALL BE			
			CHARACTER	RISTIC	CAP. CHANGE	SUBJ	ECT	ED TO A HARM	ONIC MOTION
		CAPACITANCE		I	WITHIN +/-2.5% OR +/-0.25pF WHICHEVER	HAVING A TOTAL AMPLITUDE OF 1.5mm.		TUDE OF Y RANGE.	
	VIBRATION		01.400			FRO	M 10) TO 55Hz AND	RETURN
11	TEST		CLASS	В	WITHIN #/-5%	TO 10Hz, SHALL BE TRAVERSED			
			11	F	WITHIN +/-20%	IN 1	MINU	JTE.	
		Q	30pF AND C	OVER: (Q>= 1000				
			LESS THAN	30pF :		THIS	CYC	LE SHALL BE	PERFORMED
					SFEUIFIED	2 HO	URS	IN EACH THEF	RE MUTUALLY
					SPECIFIED		TO"		
		RESISTANCE	INITIAL VA	LUE.		TOX TOTAL FERIOD OF 6 HOURS.			

* THE INITIAL VALUE OF CLASS II MLCC SHALL BE MEASURED AFTER THE HEAT TREATMENT OF 150 +0/-10C ,1Hr AND SITTING OF 48+/-4hr AT ROOM TEMPERATURE & ROOM HUMIDITY.

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Multilayer Chip Capacitors - Array

NO	IT	PERFORMANCE				TEST CONDITION	
		APPEARANCE	NO MECH	IANICAL D	AMAG	E SHALL OCCUR.	
			CHARACTERISTIC		CAPACITANCE CHANGE		
					WITH	IN +/-5% OR	
		CAPACITANCE	CLA	SS I	+/-0.5	uF WHICHEVER	TEMPERATURE : 40+/-2 C
					IS LA	RGER	RELATIVE HUMIDITY:90~95 %RH
			CLASS	В	WITH	IN +/-12.5%	TEST TIME : 500 +12/-0 Hr.
				F	WITH	IN +/-30%	-
12	HUMIDITY (STEADY	Q CLASS I	30pF AND 10 ~30pF LESS THA	OVER : : Q>= N 10pF :	Q>= 3 : 275 + Q>= 2	350 - 2.5C 00 + 10C	MEASURE AT ROOM TEMPERATURE AFTER COOLING FOR CLASS I : 24+/-2 Hr.
	STATE)		CHAR.	25V : ove	and er	16V	CLASS II : 48+/-4 Hr.
		Tan delta	в	0.05 MA	5 X	0.05 MAX	
		CLASS II		0.07 MA	75 X	0.1 MAX (C<1.0uF) 0.125 MAX (C>=1.0uF)	
		INSULATION RESISTANCE	MINIMUM 1,000 Mol WHICHEV	INSULATI nm OR 50 ER IS SM	ON RE Mohm (MALLEF	SISTANCE: uF PRODUCT R.	
		APPEARENCE	NO MECH	IANICAL D	AMAG	E SHALL OCCUR.	
			CHARACTERISTIC		C	APACITANCE CHANGE	APPLIED VOLTAGE :
		CAPACITANCE	CLA	SS I	WITHI +/-0.7	IN +/-7.5% OR 5uF WHICHEVER	RATED VOLTAGE TEMPERATURE : 40+/-2 C
						RGER	RELATIVE HUMIDITY:90~95%RH
			CLASS	В	WITH	IN +/-12.5%	TEST TIME : 500 +12/-0 Hr.CURRENT
			П	F	WITH	IN +/-30%	APPLIED : 50mA MAX.
12		Q CLASS I	30pFANE	OVER : BELOW	Q>= 2 : Q>=	200 100 + 10/3C	MEASUREING AT ROOM
13	RESISTANCE		CHAR.	25V an over	d	16V	TEMPERATURE AFTER COOLING FOR
		Tan delta	В	0.05 MAX		0.05 MAX	CLASS I : 24+/-2 Hr. CLASS II : 48+/-4 Hr.
		CLASS II	F	0.075 MAX		0.1 MAX (C<1.0uF) 0.125 MAX (C>=1.0uF)	
		INSULATION RESISTANCE	MINIMUM INSULATI 500 Mohm OR WHICHEVER IS		ON RESISTANCE: 25Mohm uF PRODUCT, S SMALLER.		



Multilayer Chip Capacitors - Array

	NO	ITEM		PERFORMANCE			TEST CONDITION				
	14		APPEARANCE	NO MECHANICAL DAMAGE SHALL OCCUR.							
		HIGH TEMPERATURE RESISTANCE	CAPACITANCE	CHARAC	TERISTIC	CAP. CHANGE					
				CLASS I		WITHIN +/-3% OR +/-0.3pF,WHICHEVER IS LARGER	APPLIED VOLTAGE : 200% OF RATED VOLTAGE TEST TIME : 1000 +48/-0 Hr. CURRENT APPLIED : 50mA MAX.				
				CLASS	В	WITHIN +/-12.5%					
					F	WITHIN +/-30%		CHAR.		TEMP.	
			Q CLASS I	30pF AND OVER : Q >= 350		CLASS I 1			125 +/-3 C		
				LESS THAN $10pF : Q \ge 200 + 10C$			CLASS B 12			125 +/-3 C	
			Tan delta CLASS II	CHAR.	25V and over	16V			F	85 +/-3 C	
				В	0.05 MAX	0.05 MAX	(INITIAL VALUE MEASUREMENT) FOR CLASS II CAPACITORS, 200 % OF RATED VOLTAGE SHALL BE APPLIED FOR 1 HOUR AT THE				
				F	0.075 MAX	0.1 MAX (C<1.0uF) 0.125 MAX (C>=1.0uF)					b
			INSULATION RESISTANCE	MINIMUM 1,000 Moi WHICHEV	THEN KEEP IT AT ROOM TEMPERATURE. FOR 48 +/- 4 Hrs.						
	15	TEMPERATURE CYCLE	APPEARANCE	NO MECH	CAPACITORS SHALL BE SUBJECTED						
			CAPACITANCE	CHARAC	TERISTIC	CAP. CHANGE	TO FIVE CYCLES OF THE				
						WITHIN +/-2.5%		TURE	CYCLE	AS FOLLOV	VING T
				CLASS I		OR +/-0.25pF WHICHEVER IS	STEP	TE	MP.(C)	TIME (MIN)	
						LARGER		I	MIN.]
				CLASS	В	WITHIN +/-7.5%	1 1	RATE	D TEMP.	30	
				П	F	WITHIN +/-20%		-	+0/-3		-
			0	30 pE AND OVER : 0 >= 1000			2		25	2~3	-
			CLASS I	LESS THAN 30 pF : Q >= 400 + 20C		3	RATE	MAX. ED TEMP. +3/-0	30		
			Tan delta CLASS II	TO SATISFY THE SPECIFIED INITIAL VALUE			4		25	2~3	
											J
			INSULATION RESISTANCE	MINIMUM INSULATION RESISTANCE: 1,000 Mohm OR 50Mohm uF PRODUCT WHICHEVER IS SMALLER.			MEASURE AT ROOM TEMPERATURE AFTER COOLING FOR CLASS I : 24+/-2 Hr. CLASS II : 48+/-4 Hr.				